

### Features

- Low operating voltage: 5V
- Ultra low capacitance: 0.3pF(Typ)
- Ultra low leakage: nA level
- Low clamping voltage
- -IEC 61000-4-2 (ESD) immunity test
  - Air discharge:  $\pm 30\text{kV}$
  - Contact discharge:  $\pm 30\text{kV}$
- -IEC61000-4-4 (EFT) 40A (5/50ns)
- -IEC61000-4-5 (Lightning) 5.5A (8/20 $\mu\text{s}$ )
- 2-pin leadless package
- These are Pb-Free Devices
- Response Time is Typically < 1 ns

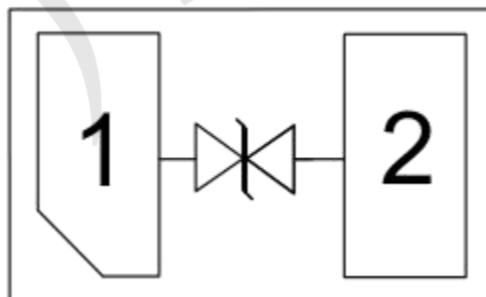
### Mechanical Characteristics

- Package: DFN1006-2(0402)
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound
- Terminal Connections: See Diagram Below
- -IEC 61000-4-2 (ESD) immunity test

### Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- USB power and data line

### Dimensions and Pin Configuration



### Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

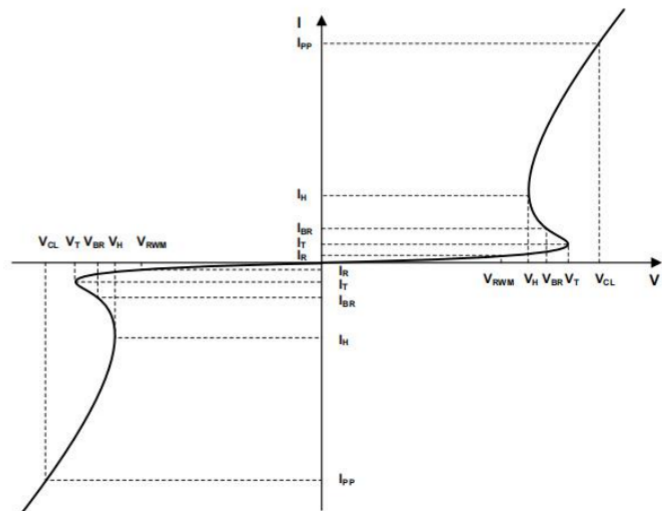
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	55	W
Peak Pulse Current (8/20μs)	Ipp	5.5	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±30 ±30	KV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

### Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM	--	--	5	V	
Breakdown Voltage	VBR	5.8	8.0	9.5	V	IT= 1mA
Reverse Leakage Current	IR	--	--	200	nA	VRWM=5V
Clamping Voltage	VC	--	5.8	7.5	V	Ipp=1A(8x 20us pulse)
Clamping Voltage	VC	--	8	10	V	Ipp=5.5A(8x 20us pulse)
Junction Capacitance	CJ	--	0.3	0.4	pF	VR = 0V, f = 1MHz

### Electrical Characteristics

Symbol	Parameter
V <sub>BR</sub>	Reverse Breakdown Voltage
I <sub>BR</sub>	Reverse Breakdown Current
V <sub>RWM</sub>	Reverse Stand-off Voltage
I <sub>R</sub>	Reverse Leakage Current
V <sub>H</sub>	Holding Voltage
I <sub>H</sub>	Holding Current
V <sub>T</sub>	Trigger Voltage
I <sub>T</sub>	Trigger Current
I <sub>PP</sub>	Peak Pulse Current
V <sub>CL</sub>	Clamping Voltage



### Characteristic Curves

Fig1. 8/20 $\mu$ s Pulse Waveform

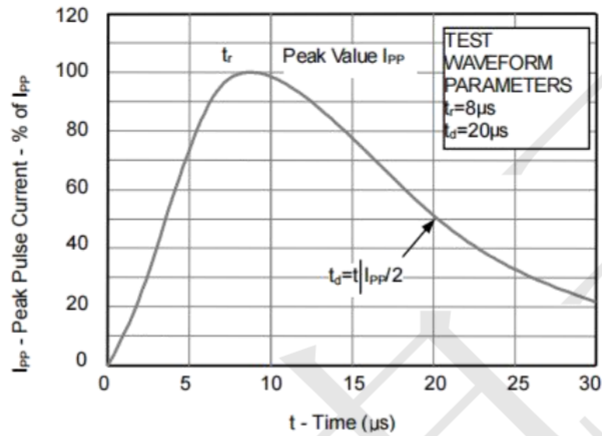


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

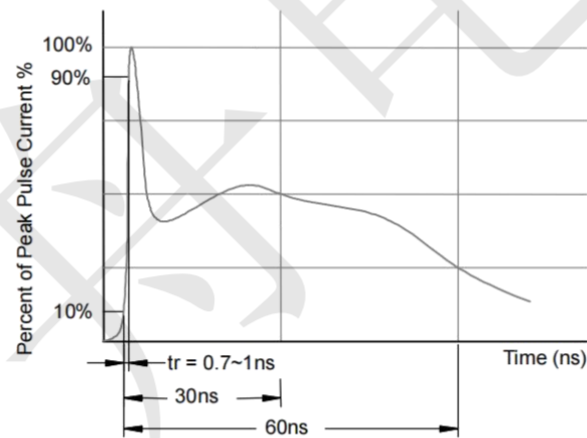
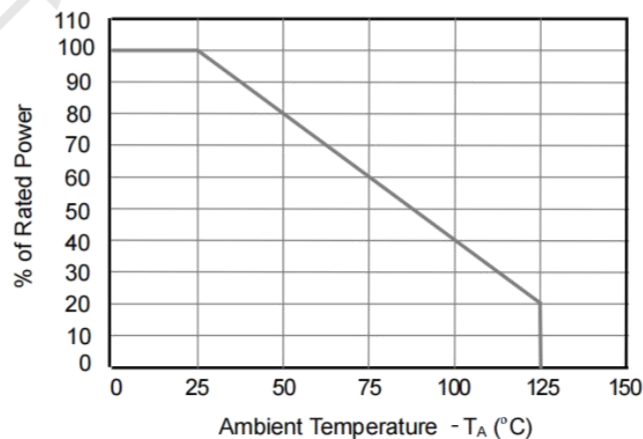
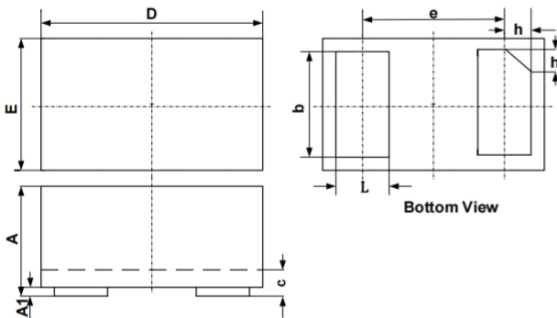


Fig3. Power Derating Curve



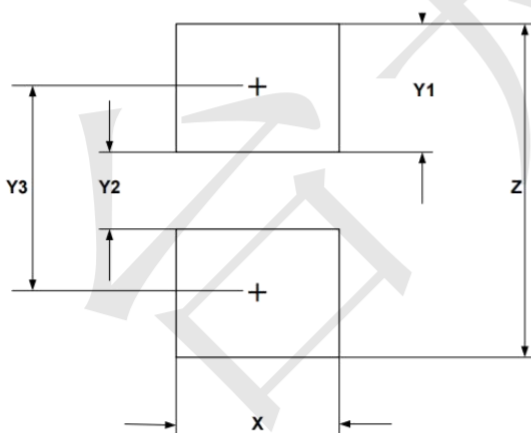
### Package Outline & Dimensions

#### DFN1006-2 (0402)



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

### Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052